

Multi-physics simulation of organic devices using LTspice for first principle understanding

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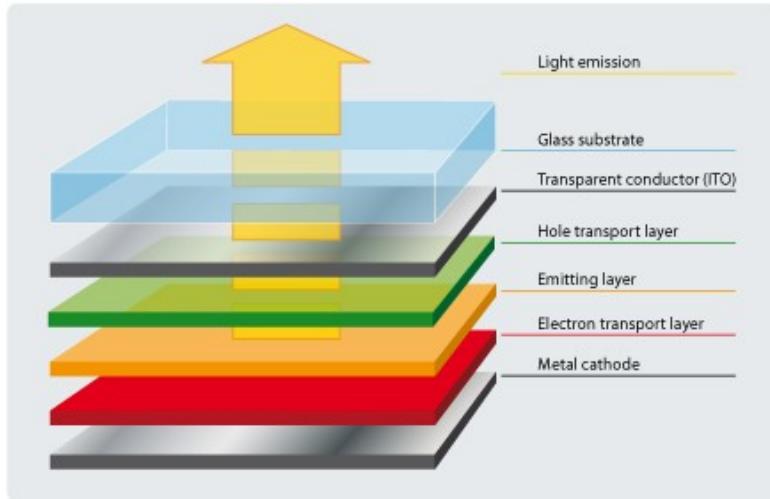
- Explaining new unexpected measurements
- Feasibility analysis of new ideas and strategies
- Short development time (~ days – weeks)
- Playground to improve understanding, basic optimization rules
- Multi-physics (charge flow, heat flow, ...)
- Design rules for sophisticated simulation tools



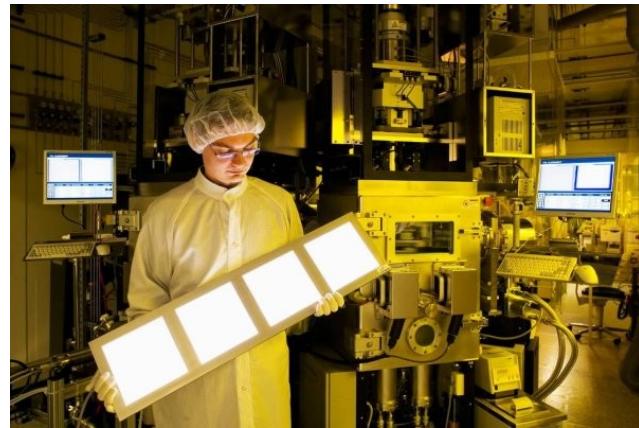
<http://www.linear.com/designtools/software/>

- SPICE (Simulation Program with Integrated Circuits Emphasis)
- Commonly used for analog electronic circuits
- Freely available (Ltpice, Ngspice,...)
- Netlist can be generated by scripts, Data output by ASCII file
- Arbitrary current and voltage sources allow for adapting problems

1. Electrothermal feedback in OLEDs
2. A new concept for organic semiconductor lasers

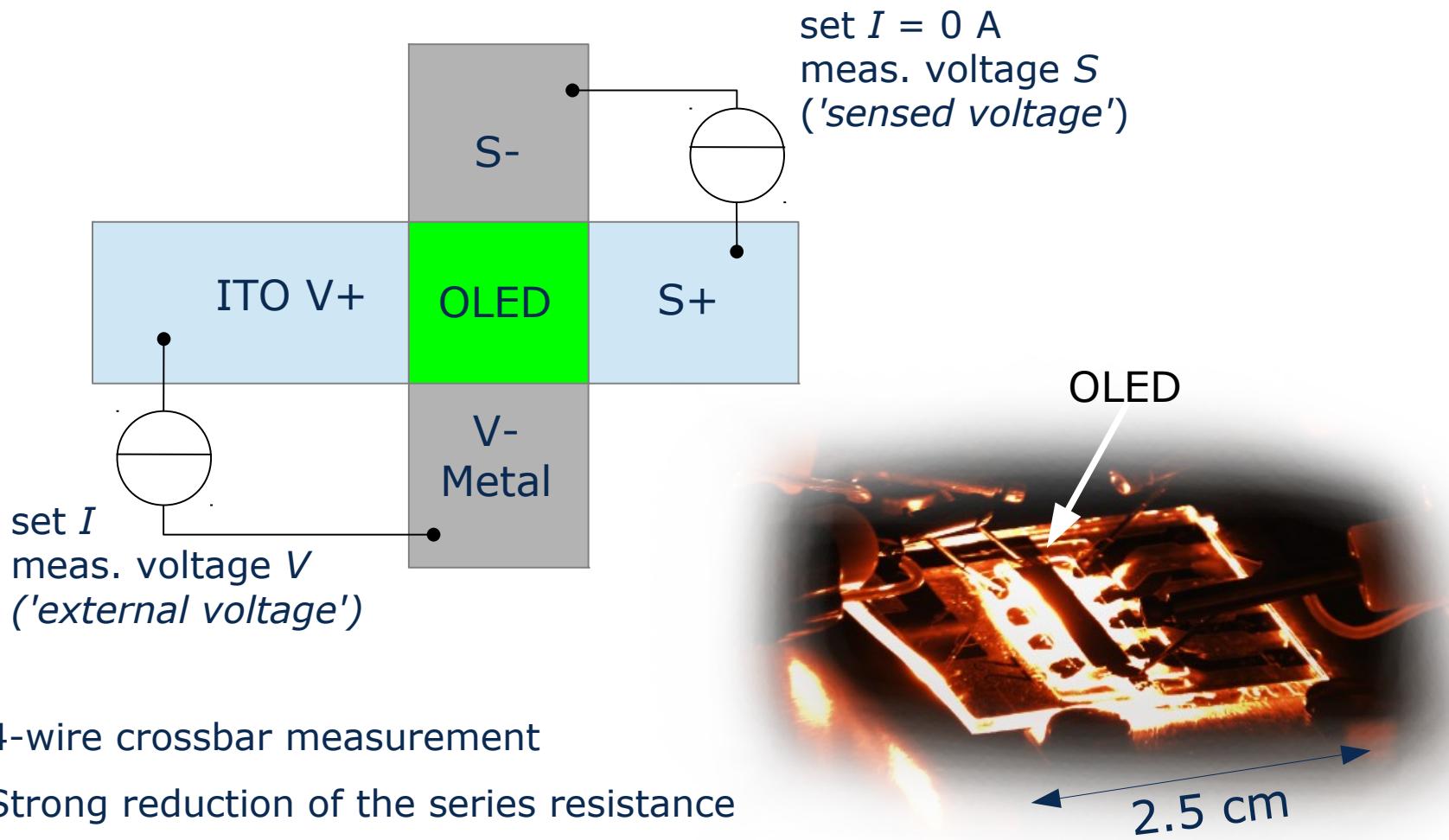


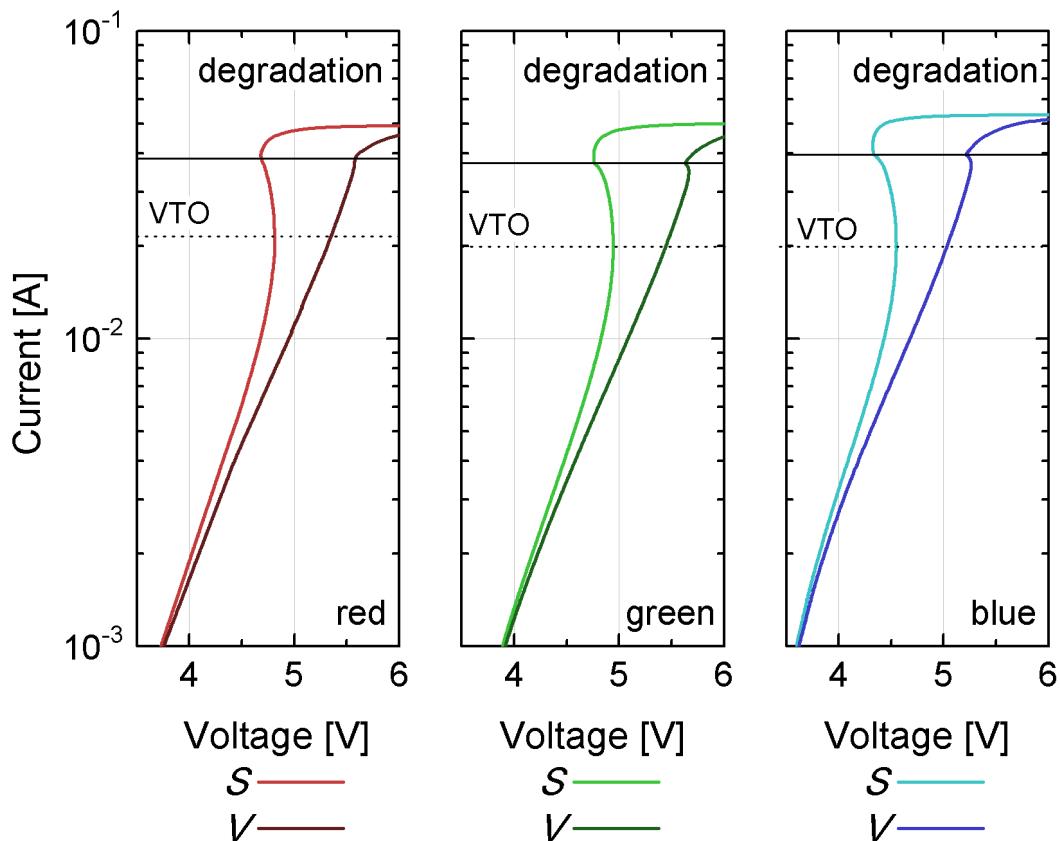
from novaled.com



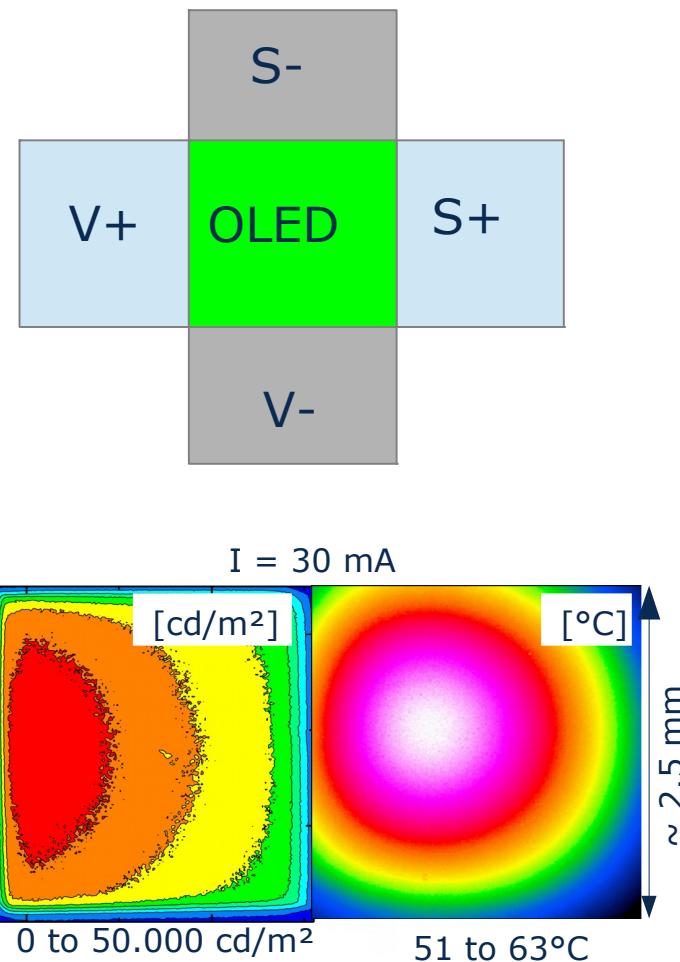
Fraunhofer COMEDD, Dresden
Lighting panel

- OLEDs are multi-layer devices composed of organic molecules
- OLEDs can be fabricated on large areas as lighting panels





- NDR present for red, green, and blue OLED
- Standard pin-OLED stacks used
- VTO = voltage turnover



Fischer et al., Adv. Funct. Mater. 24, 2014

$$\sigma = \sigma_0 \exp(-E_a/k_B T)$$

(conductivity)

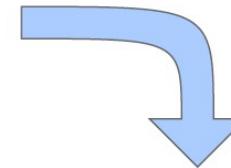
$$V = \text{const.}$$

Thermistor shows a positive feedback loop between heat dissipation and conductivity

Shaw, M. & Yildirim Thermal and Electrothermal Instabilities in Semiconductors 1983
Fischer et al., Phys. Rev. Lett. 110, 2013

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(conductivity)



$$V = \text{const.}$$

$$j = \sigma F$$

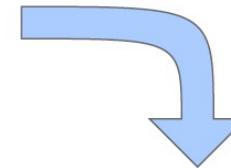
(current)

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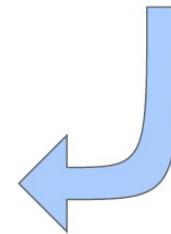
$$V = \text{const.}$$

$$j = \sigma F$$

(current)

$$P = jAV$$

(power)

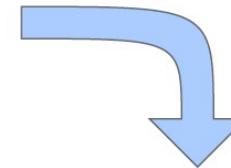


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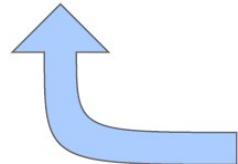
$$\sigma = \sigma_0 \exp(-E_a/k_B T)$$

(conductivity)



$$\Delta T = \Theta_{th} P$$

(temperature)



$$V = \text{const.}$$

$$P = jAV$$

(power)

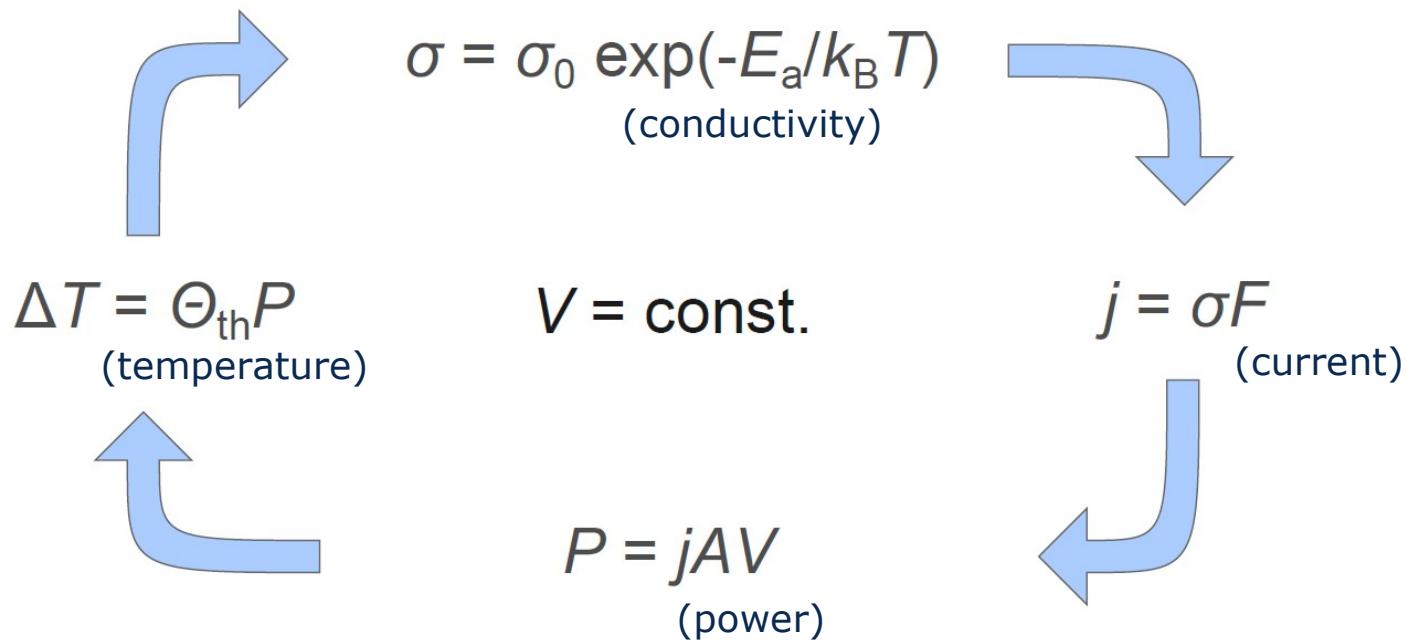
$$j = \sigma F$$

(current)



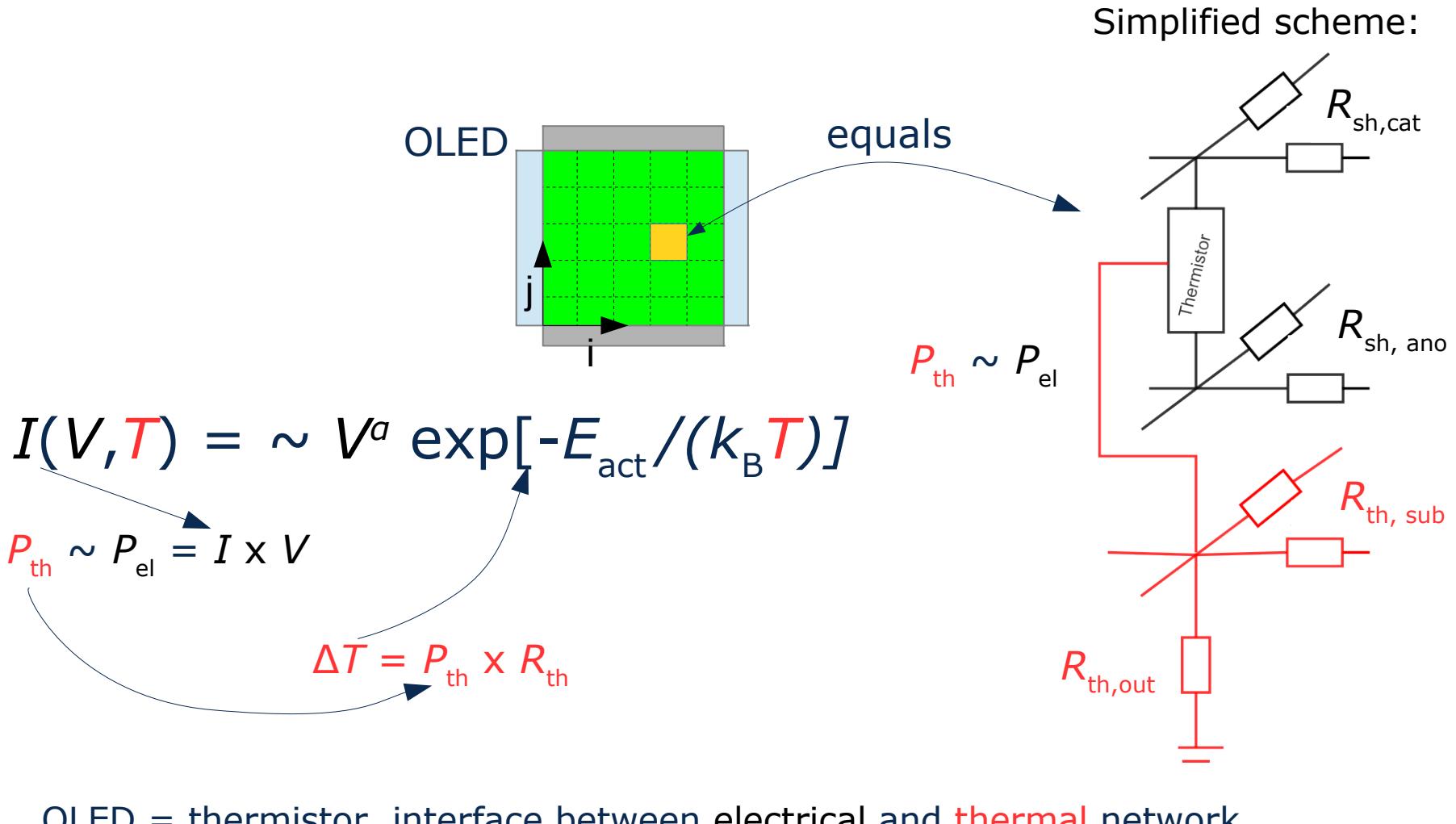
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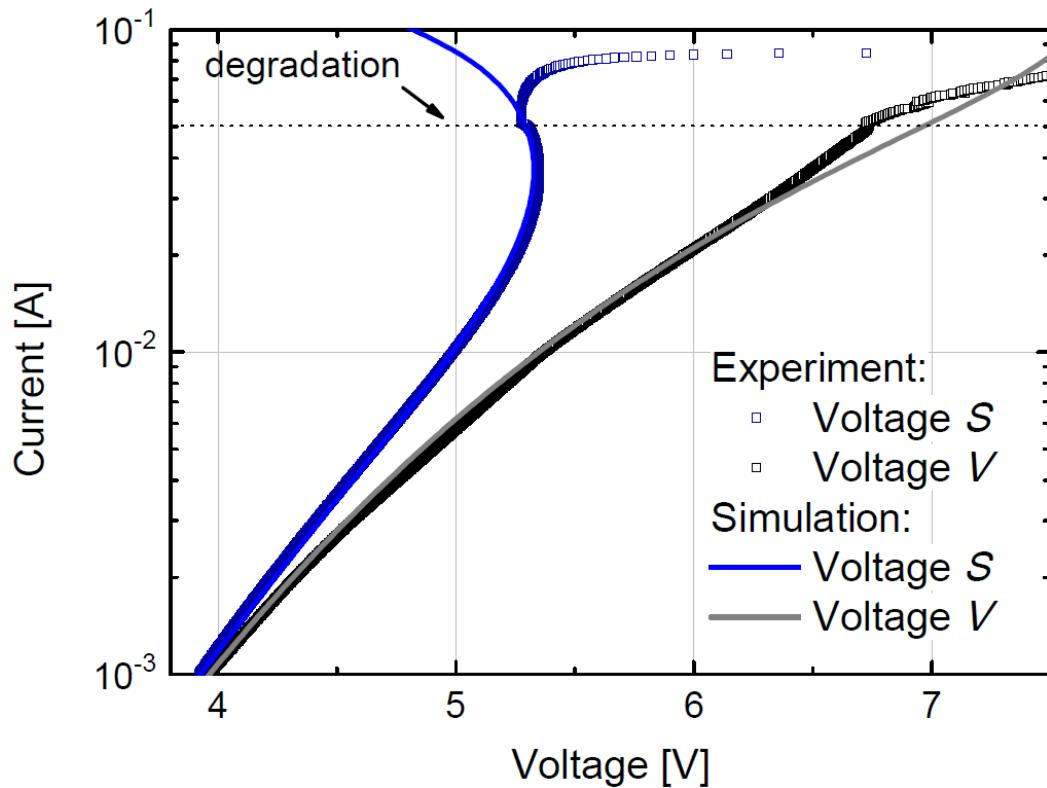


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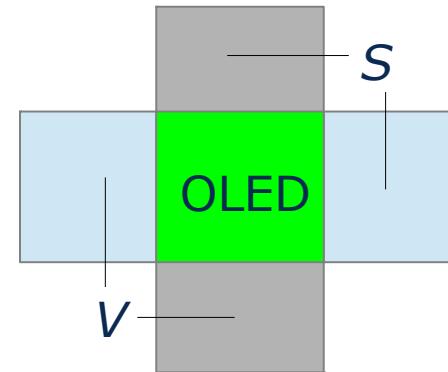
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OLED = thermistor, interface between electrical and **thermal** network



- Experimental data can be fitted until degradation starts



Fitting parameter:

$$E_{\text{act}} = 25 \text{ } k_{\text{B}} T$$

Exponent = 8.9

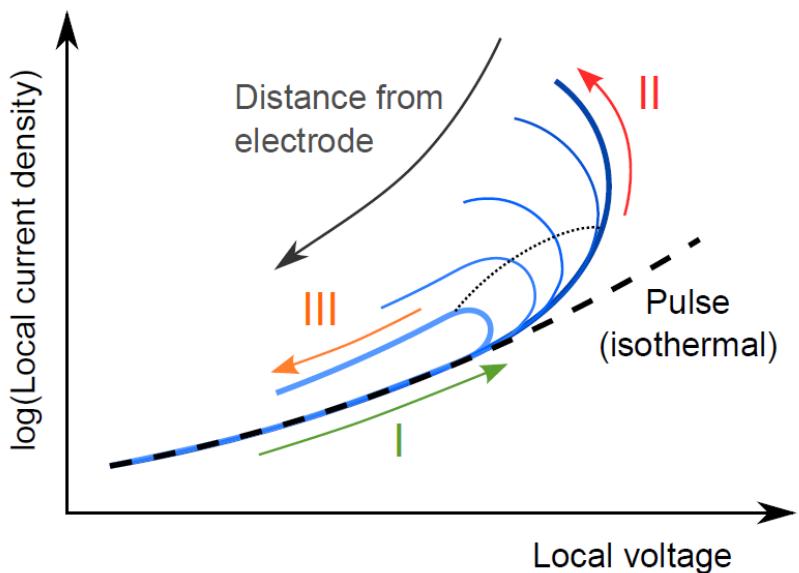
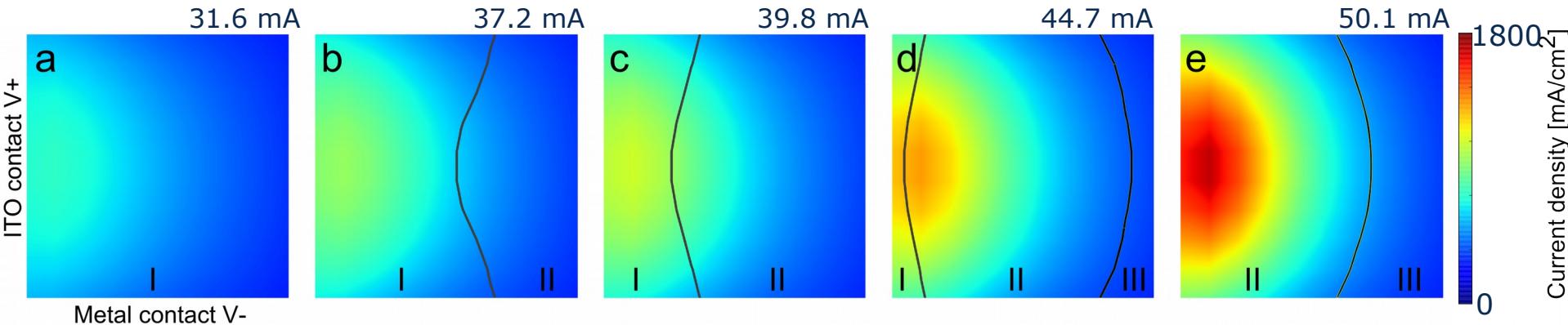
Fixed parameters:

$$R_{\text{sh}} = 26.5 \Omega \text{ (experiment)}$$

$$V_{\text{ref}}, I_{\text{ref}} = 3.9 \text{ V}, 1 \text{ mA}$$

$$\lambda_{\text{glass}} \sim 1.8 \text{ W/m/K}$$

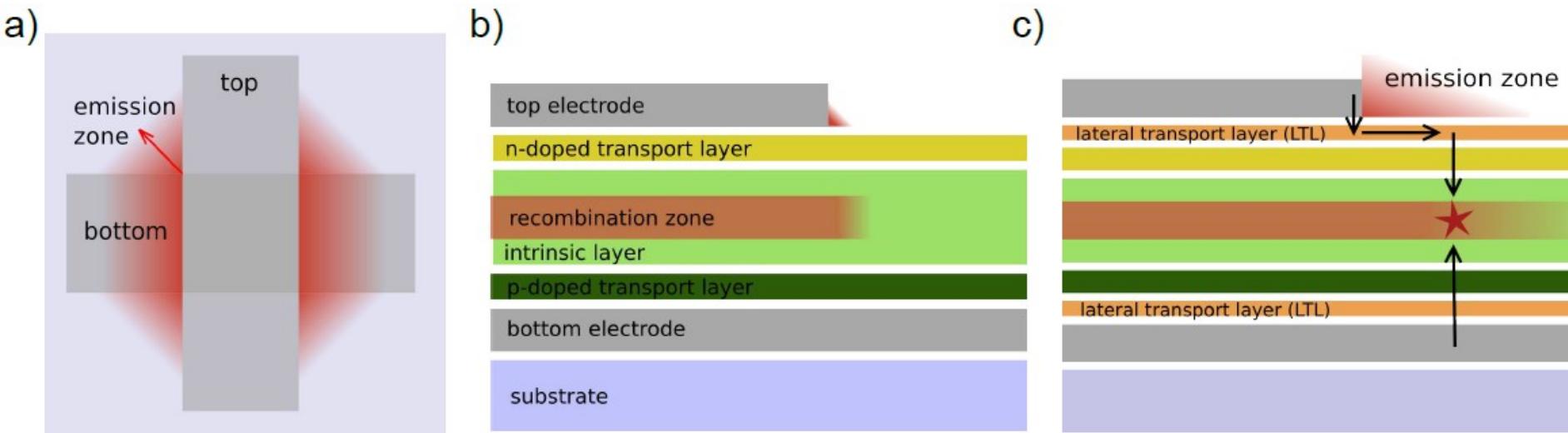
Fischer et al., Adv. Funct. Mater. 24, 2014



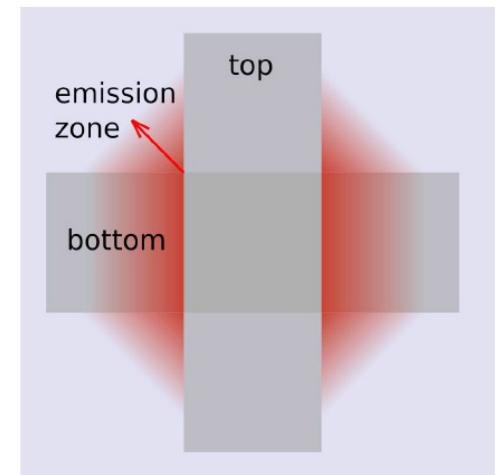
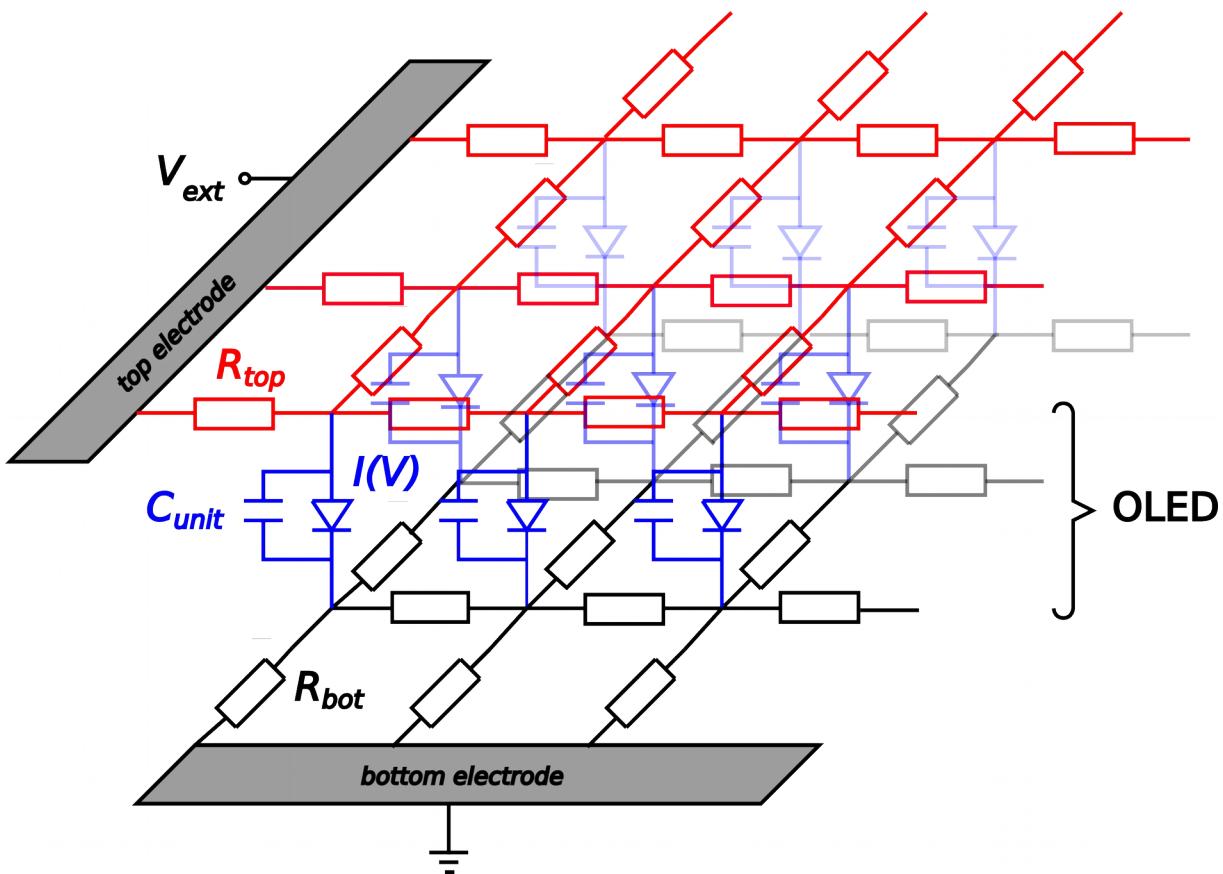
voltage	$\frac{dV_{ij}}{dI} > 0$	$\frac{dV_{ij}}{dI} < 0$
current	$\frac{dV_{ij}}{dI_{ij}} > 0$ normal (I)	$\frac{dV_{ij}}{dI_{ij}} < 0$ S-NDR (II)
	$\frac{dV_{ij}}{dI_{ij}} < 0$ N-NDR (not present)	$\frac{dV_{ij}}{dI_{ij}} > 0$ switched-back (III)

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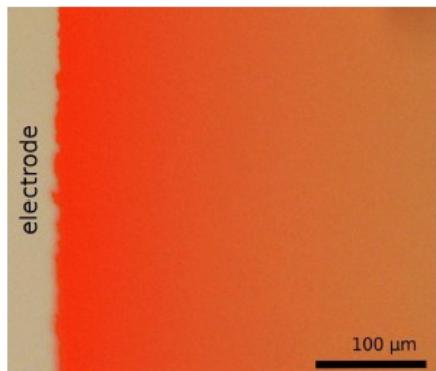


- New structuring concept for organic semiconductor laser
- Idea: Enhance light emission outside the „active area“
- Use of highly conductive layer: n-doped C₆₀ (~ 10 S/cm)

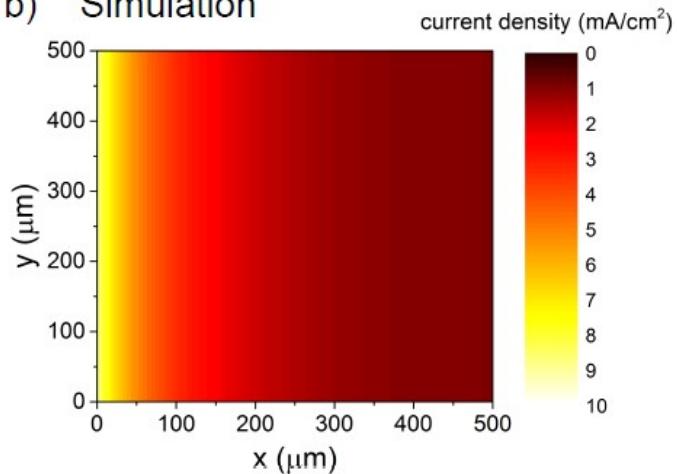


- Diodes = vertical current flow through OLED layer stack
- Resistors = lateral current flow by highly doped layers (n-doped C₆₀)

a) Emission

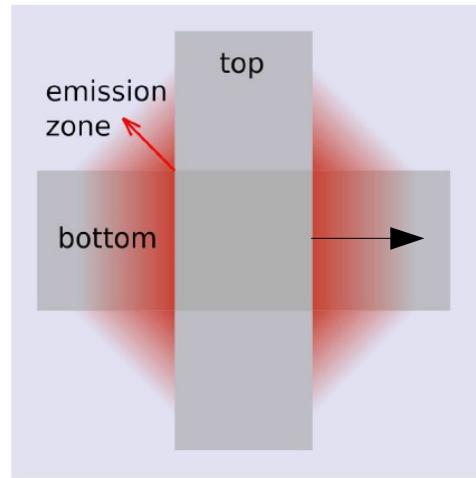
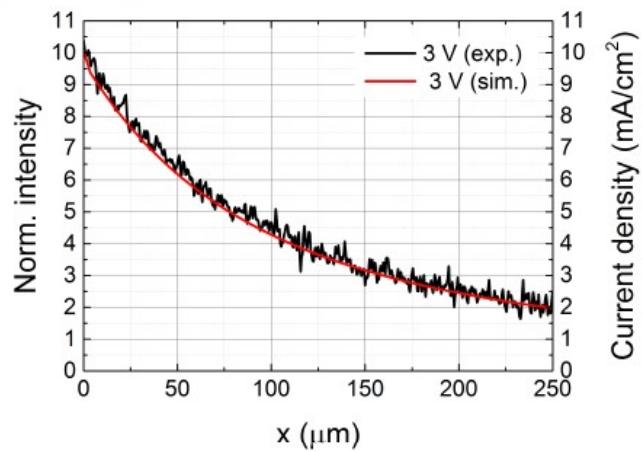


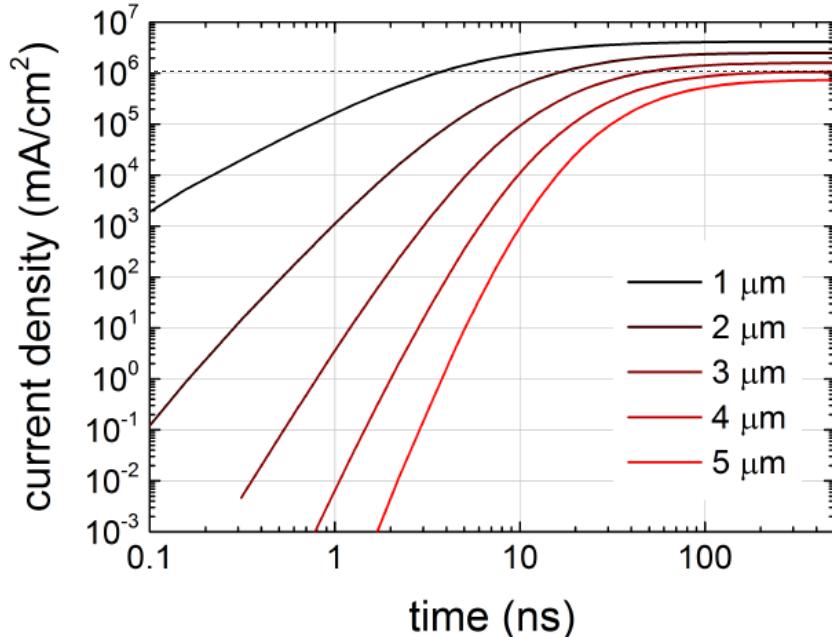
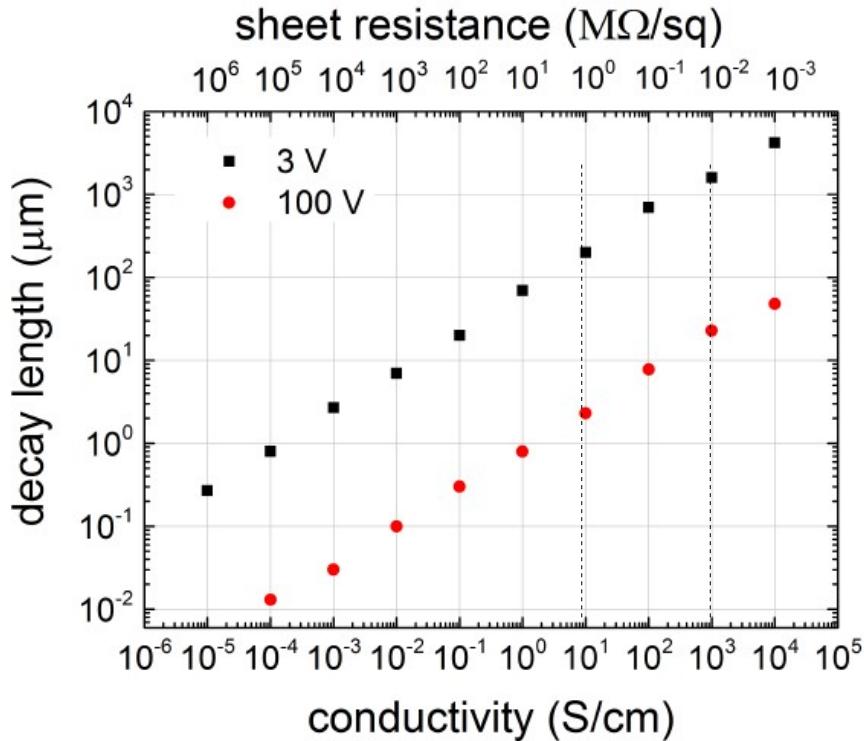
b) Simulation



- Simulation reproduces decay profile of emission outside the electrode overlap

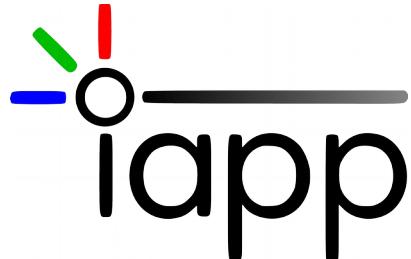
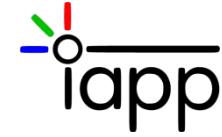
c) Comparison





- Relevant current densities are reached at $>100 \text{ V}$
- After 40 ns, $1 \text{ kA}/\text{cm}^2$ are achieved within a distance of 3 μm
- Higher conductivity desirable \rightarrow PEDOT:PSS 1000 S/cm

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German Academic Exchange Service

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